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场效应器件表面修饰对DNA测试性能影响的研究

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摘 要

对比甲醇一盐酸混合物及硫酸处理对场效应器件(Field-effect device,FED)电化学测试性能的影响。实验结果表明,FED表面经过两种方式处理,其电化学阻抗测试特性发生变化,表现在阻抗的虚部值(用Zq表示)随加在FED器件与参比电极之间的电压的变化特性(用Zq-V曲线表示)发生改变。经过硫酸处理的器件的Zq-V曲线相对于未处理器件有微小偏移;而甲醇-盐酸体系处理后曲线在耗尽层区的斜率有所下降,表明这种处理对器件测试性能有负向的影响。经硅烷化固定在表面的氨基采用荧光标记,荧光测试结果表明,两种表面处理方式对硅烷化效果影响不大。进一步通过共价连接在硅烷化FED表面引入探针DNA分子,制备基于FED的DNA传感器。与目标DNA分子杂交反应后,实验表明,硫酸处理的测试结果要好于甲醇一盐酸的处理方法。

关键词: 场效应器件,表面修饰, 硅烷化, DNA传感器

The research of the influence of surface modification on the DNA test characteristics of field effect devices

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Abstract

The influence of the surface modification on the test characteristics of the field effect devices (FED) has been studied. The surface modification was carried out employing sulfuric acid and methanol-HCl solution respectively. The test characteristics were illustrated by the measurement of the out-phase impedance (referred to as Zq) vs bias voltage imposed between the FED and the reference electrode. The Zq-V curves are different after different surface modifications. With the sulfuric acid treatment, the Zq-V curve changes little, while the treatment by the methanol-HCl solution will cause the decrease of the sensitivity of the FED. The silanization and fluorescin-labeling of the surface after these two kinds of treatment reveal that the treatments cause little influence on the silanization effect of the surface. The FED-based DNA sensors were prepared after the surface modification of the FED. The methanol-HCl treatment will make the readout of the DNA sensor decreased compared with the sulfuric acid treatment.

Keywords: field effect device, surface modification, silanization, DNA sensor

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